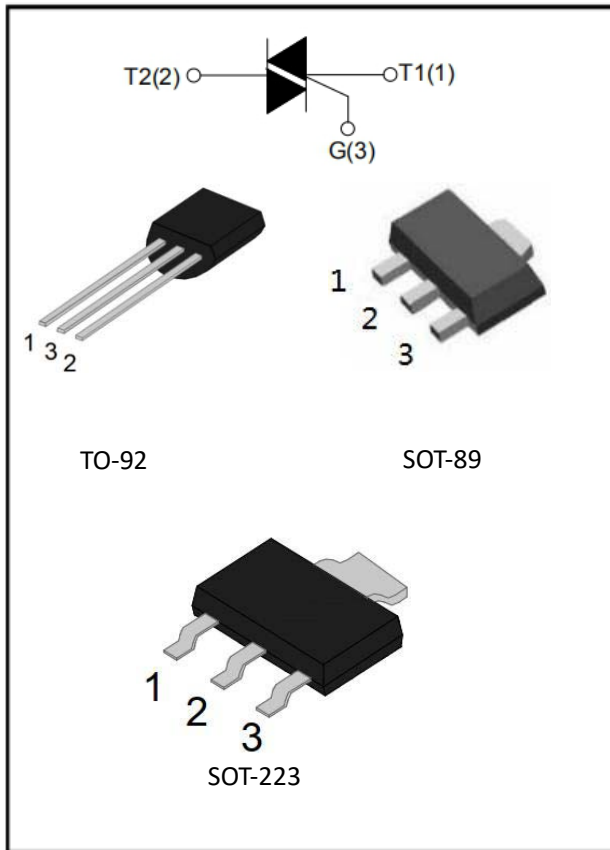


1A SCRs



Features

- On-state rms current, $I_{T(RMS)}$ 1 A
- Repetitive peak off-state voltage, V_{DRM}/V_{RRM} 800 V
- Triggering gate current, $I_{GT(Q1)}$ 5 mA

Applications

- General purpose switching and phase control
- General purpose low power switching
- Solid-state relay

Mechanical Data

- Case Material: "Green" Molding Compound
- Package:

DEVICE	PACAKGE
ACY0810S2	SOT-223
ACY0810S3	SOT-89
ACY0810T9	TO-92

Main Characteristics

SYMBOL	LIMITS	UNIT
$I_{T(RMS)}$	1	A
V_{DRM}/V_{RRM}	800	V
I_{GT}	5	mA

Maximum Ratings

PARAMETER	SYMBOL	LIMITS	UNIT
Storage junction temperature range	Tstg	-40~150	°C
Operating junction temperature range	Tj	-40~125	°C
Repetitive surge peak Off-state voltage (Tj=25°C)	V_{DRM}	800	V
Repetitive peak reverse voltage (Tj=25°C)	V_{RRM}	800	V
RMS on-state current (TC=80°C)	$I_{T(RMS)}$	1	A
Non-repetitive surge peak on-state current (full cycle, F=50Hz)	I_{TSM}	16	A
I^2t value for fusing (tp=10ms)	I^2t	1.28	A ² s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$)	di/dt	I - II - III	50
		IV	10
Peak gate current	I_{GM}	2	A
Average gate power dissipation	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	5	W



ACY0810 Series

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	QUADRANT	MIN	TYP	MAX
Gate trigger current	I _{GT}	mA	V _D =12V, R _L =33Ω	I - II - III			5
				IV			10
Gate trigger voltage	V _{GT}	V	V _D =12V, R _L =33Ω	I - II - III - IV			1.3
Non-triggering gate voltage	V _{GD}	V	V _D =V _{DRM}	I - II - III - IV	0.2		
Holding current	I _H	mA	I _T =100mA	I - II - III - IV			7
Latching current	I _L	mA	I _G =1.2 I _{GT}	I - III - IV			5
				II			20
Rate of rise of off-state voltage	dV/dt	V/μs	V _D =0.66×V _{DRM} T _j =125°C Gate open	I - II - III - IV	50		

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MAX
Peak on-state voltage	V _{TM}	V	I _{TM} =1.4A t _p =380μS	1.5
Peak off-state current Peak reverse current	I _{DRM} I _{RRM}	μA	V _{DRM} = V _{R_{RM}} , T _j =25°C	5
		mA	V _{DRM} = V _{R_{RM}} , T _j =125°C	0.5

■Thermal Resistance (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	Pacakge	Value	
Thermal Resistance (Typical)	Junction to case	R _{θJ-C}	°C/W	TO-92	60
			°C/W	SOT-89/SOT-223	31



■ Characteristics (Typical)

FIG.1: Maximum power dissipation versus RMS on-state current

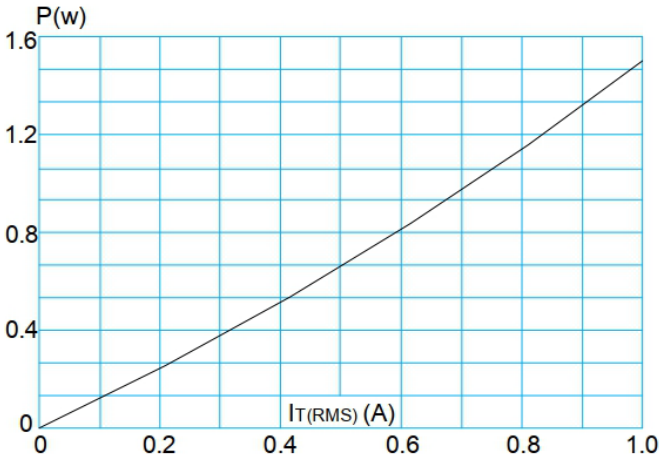


FIG.2: RMS on-state current versus case temperature

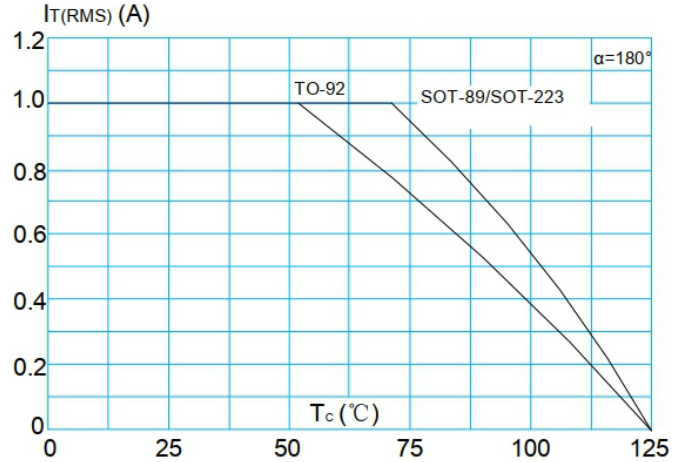


FIG.3: Surge peak on-state current versus number of cycles

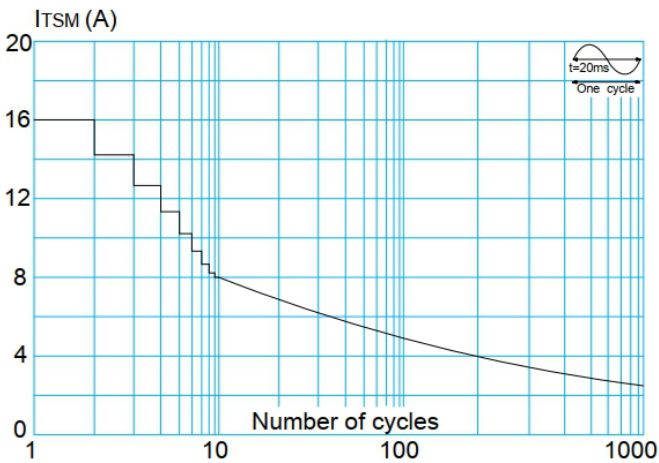


FIG.4: On-state characteristics (maximum values)

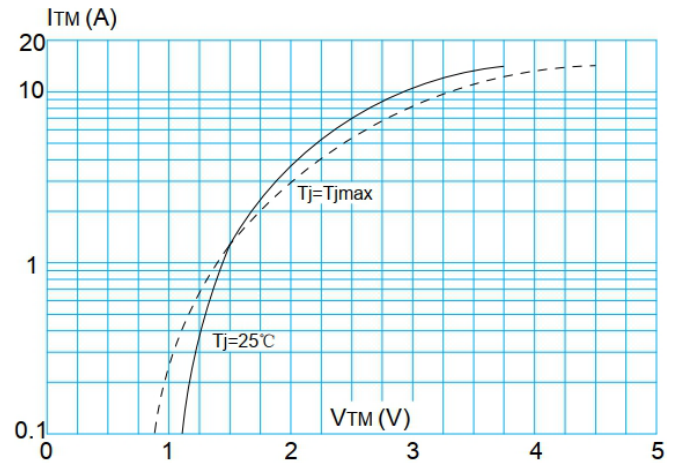


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of $I_2 t$ ($di/dt < 50\text{A}/\mu\text{s}$)

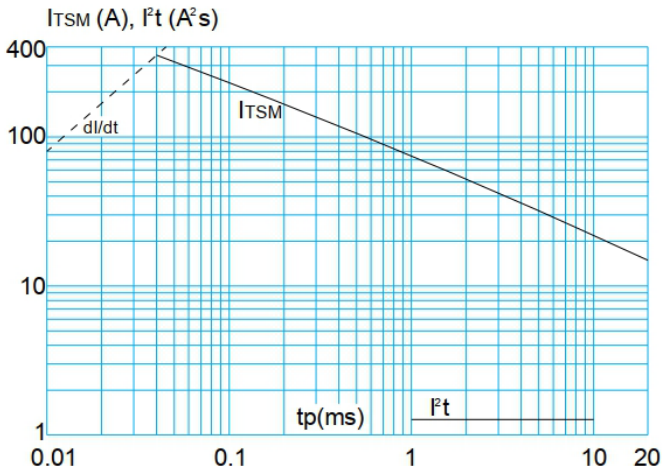
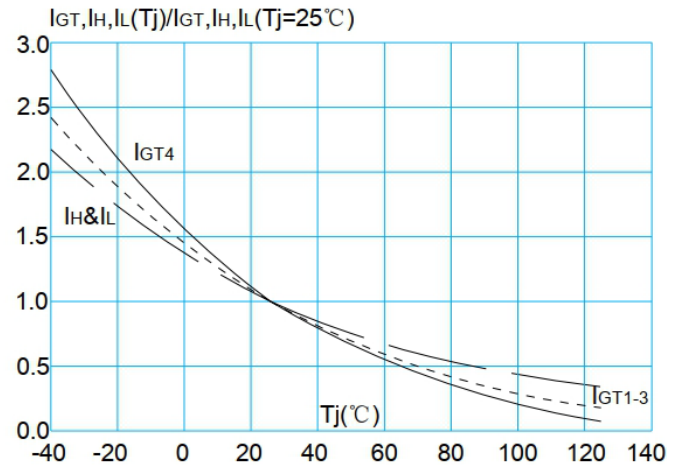


FIG.6: Relative variations of gate trigger current, holding current and latching

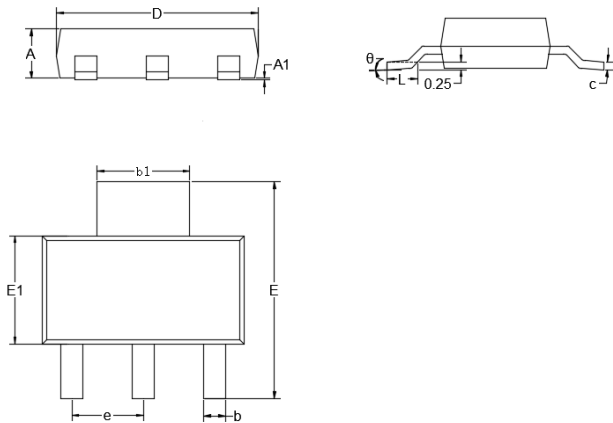




ACY0810 Series

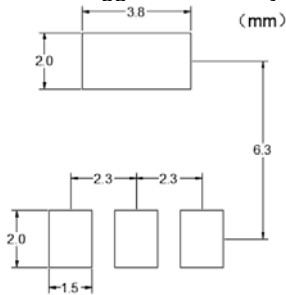
■ Outline Dimensions

➤ SOT-223 Package Outline Dimensions

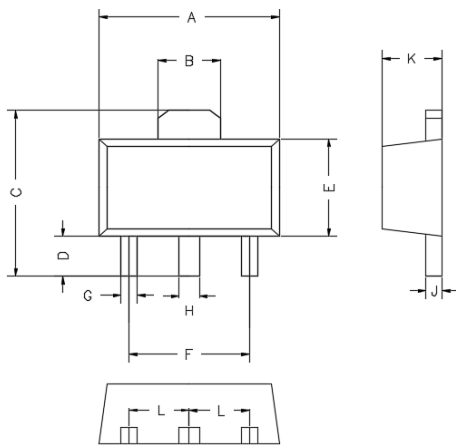


DIM	DIMENSIONS			
	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.0591	0.0670	1.5000	1.7000
A1	0.0008	0.0039	0.0200	0.1000
b	0.0259	0.0330	0.6600	0.8400
b1	0.1140	0.1220	2.9000	3.1000
c	0.0090	0.0138	0.2300	0.3500
D	0.2480	0.2640	6.3000	6.7000
E	0.2637	0.2874	6.7000	7.3000
E1	0.1290	0.1460	3.3000	3.7000
e	0.0866	0.0945	2.2000	2.4000
L	0.0295	0.0492	0.7500	1.2500
θ	0°	10°	0°	10°

SOT-223 Suggested Pad Layout

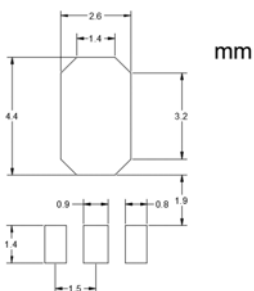


➤ SOT-89 Package Outline Dimensions



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.169	0.185	4.30	4.70	
B	0.061		1.55		TYP
C	0.154	0.171	3.91	4.35	
D	0.031	0.047	0.80	1.20	
E	0.089	0.104	2.25	2.65	
F	0.118		3.00		TYP
G	0.013	0.020	0.33	0.52	
H	0.016	0.023	0.40	0.58	
J	0.014	0.017	0.35	0.44	
K	0.055	0.063	1.40	1.60	
L	0.059		1.50		TYP

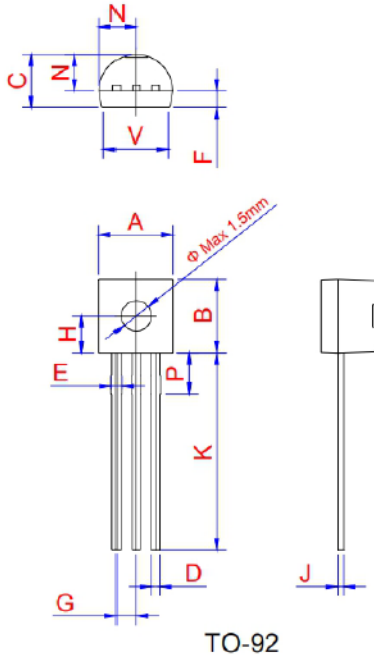
SOT-89 Suggested Pad Layout





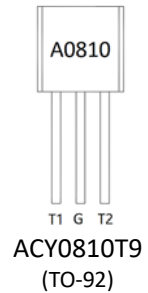
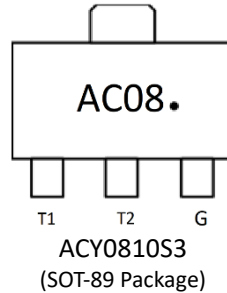
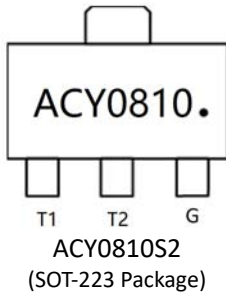
ACY0810 Series

➤ TO-92 Package Outline Dimensions



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.45	4.6	5.2	0.175	0.181	0.205
B	4.32	4.6	5.33	0.17	0.181	0.21
C	3.18	3.55	4.19	0.125	0.14	0.165
D	0.407		0.533	0.016		0.021
E	0.6		0.8	0.024	0	0.031
F	-	1.1	-	-	0.043	-
G	-	1.27	-	-	0.05	-
H	-	2.3	-	-	0.091	-
J	0.36	0.38	0.5	0.014	0.015	0.02
K	12.7		15	0.5		0.591
N	2.04	2.3	2.66	0.08	0.091	0.105
P	1.86		2.06	0.073		0.081
V	-		4.3	-		0.169

■ Marking Information



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ACY0810 Series

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